

54ABT16245

16-Bit Transceiver with TRI-STATE® Outputs

General Description

The 'ABT16245 contains sixteen non-inverting bidirectional buffers with TRI-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The T/R inputs determine the direction of data flow through the device. The OE inputs disable both the A and B ports by placing them in a high impedance state.

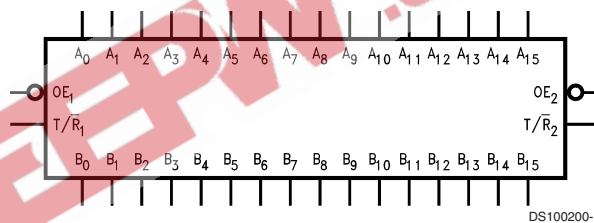
- Separate control logic for each byte
- 16-bit version of the 'ABT245
- A and B output sink capability of 48 mA, source capability of 24 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability
- Standard Microcircuit Drawing (SMD) 5962-9317501

Features

- Bidirectional non-inverting buffers

Military	Package Number	Package Description
54ABT16245W-QML	WA48A	48-Lead Cerpack

Logic Symbol



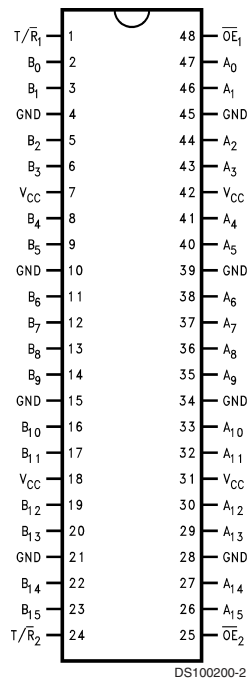
Pin Description

Pin Names	Description
\overline{OE}_n	Output Enable Input (Active Low)
T/\overline{R}_n	Transmit/Receive Input
A_0-A_{15}	Side A Inputs/Outputs
B_0-B_{15}	Side B Inputs/Outputs

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

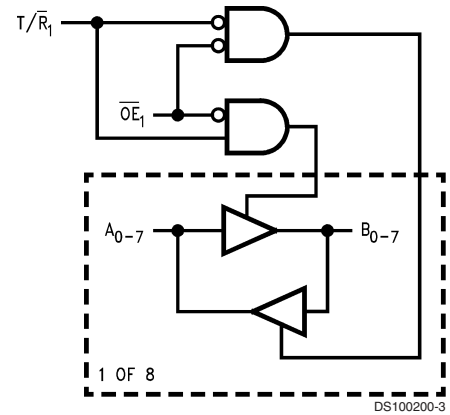
Connection Diagram

Pin Assignment for Cerpack

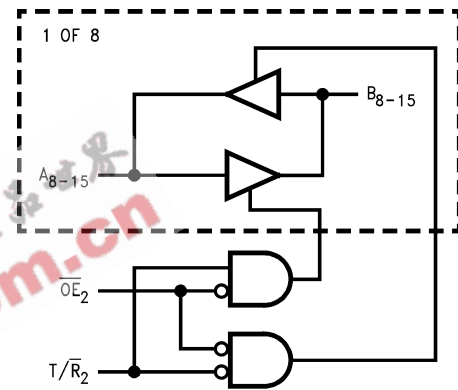


DS100200-2

Logic Diagrams



DS100200-3



DS100200-4

Functional Description

The 'ABT16245 contains sixteen non-inverting bidirectional buffers with TRI-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Inputs		Outputs
\overline{OE}_1	T/\overline{R}_1	
L	L	Bus B_0-B_7 Data to Bus A_0-A_7
L	H	Bus A_0-A_7 Data to Bus B_0-B_7
H	X	HIGH-Z State on A_0-A_7, B_0-B_7

Inputs		Outputs
\overline{OE}_2	T/\overline{R}_2	
L	L	Bus B_8-B_{15} Data to Bus A_8-A_{15}
L	H	Bus A_8-A_{15} Data to Bus B_8-B_{15}
H	X	HIGH-Z State on A_8-A_{15}, B_8-B_{15}

H = High Voltage Level
 L = Low Voltage Level
 X = Immaterial
 Z = High Impedance

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	-65°C to +150°C
Ambient Temperature under Bias	-55°C to +125°C
Junction Temperature under Bias	
Ceramic	-55°C to +175°C
V _{CC} Pin Potential to	
Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-off State	-0.5V to 5.5V
in the HIGH State	-0.5V to V _{CC}

Current Applied to Output

in LOW State (Max)

twice the rated I_{OL} (mA)

DC Latchup Source Current

-500 mA

Over Voltage Latchup (I/O)

10V

Recommended Operating Conditions

Free Air Ambient Temperature

Military

-55°C to +125°C

Supply Voltage

Military

+4.5V to +5.5V

Minimum Input Edge Rate

(ΔV/Δt)

Data Input

50 mV/ns

Enable Input

20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	ABT16245			Units	V _{CC}	Conditions
		Min	Typ	Max			
V _{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA (\overline{OE}_n , T/ \overline{R}_n)
V _{OH}	Output HIGH Voltage	54ABT	2.5		V	Min	I _{OH} = -3 mA (A _n , B _n)
		54ABT	2.0		V	Min	I _{OH} = -24 mA (A _n , B _n)
V _{OL}	Output LOW Voltage	54ABT		0.55	V	Min	I _{OL} = 48 mA (A _n , B _n)
I _{IH}	Input HIGH Current			5	μA	Max	V _{IN} = 2.7V (\overline{OE}_n , T/ \overline{R}_n) (Note 3)
				5	μA	Max	V _{IN} = V _{CC} (\overline{OE}_n , T/ \overline{R}_n)
I _{BVI}	Input HIGH Current Breakdown Test			7	μA	Max	V _{IN} = 7.0V (\overline{OE}_n , T/ \overline{R}_n)
I _{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	μA	Max	V _{IN} = 5.5V (A _n , B _n)
I _{IL}	Input LOW Current			-5	μA	Max	V _{IN} = 0.5V (\overline{OE}_n , T/ \overline{R}_n) (Note 3)
				-5	μA	Max	V _{IN} = 0.0V (\overline{OE}_n , T/ \overline{R}_n)
V _{ID}	Input Leakage Test	4.75			V	0.0	I _{ID} = 1.9 μA (\overline{OE}_n , T/ \overline{R}_n) All Other Pins Grounded
I _{IH} + I _{OZH}	Output Leakage Current			50	μA	0 – 5.5V	V _{OUT} = 2.7V (A _n , B _n); \overline{OE} = 2.0V
I _{IL} + I _{OZL}	Output Leakage Current			-50	μA	0 – 5.5V	V _{OUT} = 0.5V (A _n , B _n); \overline{OE} = 2.0V
I _{OS}	Output Short-Circuit Current	-100	-275		mA	Max	V _{OUT} = 0.0V (A _n , B _n)
I _{CEX}	Output High Leakage Current			50	μA	Max	V _{OUT} = V _{CC} (A _n , B _n)
I _{ZZ}	Bus Drainage Test			100	μA	0.0	V _{OUT} = 5.50V (A _n , B _n); All Others GND
I _{CCH}	Power Supply Current			100	μA	Max	All Outputs HIGH
I _{CCL}	Power Supply Current			60	mA	Max	All Outputs LOW
I _{CCZ}	Power Supply Current			100	μA	Max	\overline{OE}_n = V _{CC} , T/ \overline{R}_n = GND or V _{CC} All others at V _{CC} or GND
I _{CCT}	Additional I _{CC} /Input	Outputs Enabled	2.5		mA		V _I = V _{CC} - 2.1V
		Outputs TRI-STATE	2.5		mA	Max	\overline{OE}_n , T/ \overline{R}_n V _I = V _{CC} - 2.1V
		Outputs TRI-STATE	50		μA		Data Input V _I = V _{CC} - 2.1V All others at V _{CC} or GND

DC Electrical Characteristics (Continued)

Symbol	Parameter	ABT16245			Units	V _{CC}	Conditions
		Min	Typ	Max			
I _{CCD}	Dynamic I _{CC} No Load			0.1	mA/ MHz	Max	Outputs Open OE _n = GND, T/R _n = GND or V _{CC} One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

AC Electrical Characteristics

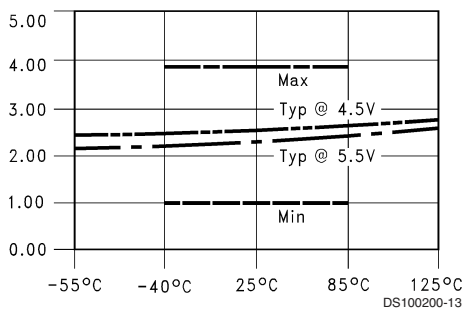
Symbol	Parameter	54ABT		Units	Fig. No.
		T _A = -55°C to +125°C V _{CC} = 4.5V-5.5V C _L = 50 pF			
		Min	Max		
t _{PLH} t _{PHL}	Propagation Delay Data to Outputs	0.5	4.5	ns	Figure 5
		0.5	5.2		
t _{PZH} t _{PZL}	Output Enable Time	0.8	6.4	ns	Figure 4
		0.9	6.9		
t _{PHZ} t _{PLZ}	Output Disable Time	1.3	6.9	ns	Figure 4
		1.0	6.9		

Capacitance

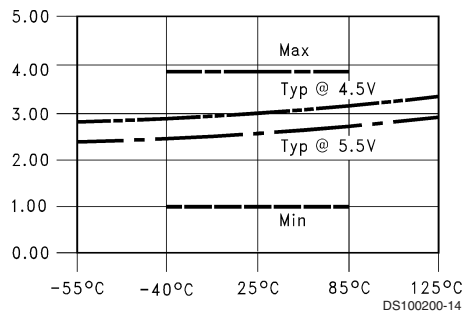
Symbol	Parameter	Typ	Units	Conditions, T _A = 25°C
C _{IN}	Input Capacitance	5	pF	V _{CC} = 0.0V (OE _n , T/R _n)
C _{I/O} (Note 4)	Output Capacitance	11	pF	V _{CC} = 5.0V (A _n , B _n)

Note 4: C_{I/O} is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

t_{PLH} vs Temperature (T_A)
C_L = 50 pF, 1 Output Switching

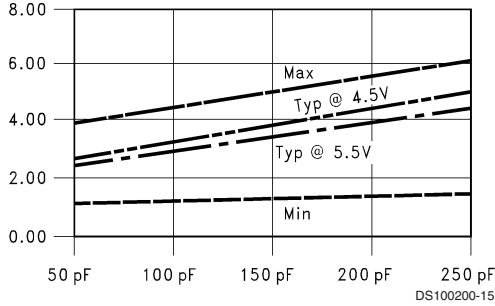


t_{PHL} vs Temperature (T_A)
C_L = 50 pF, 1 Output Switching

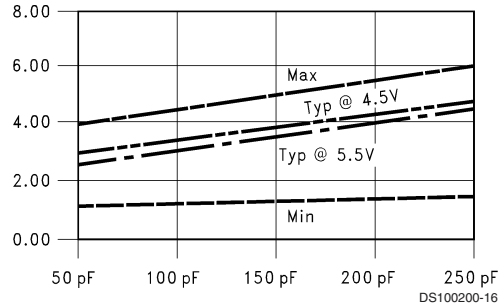


Capacitance (Continued)

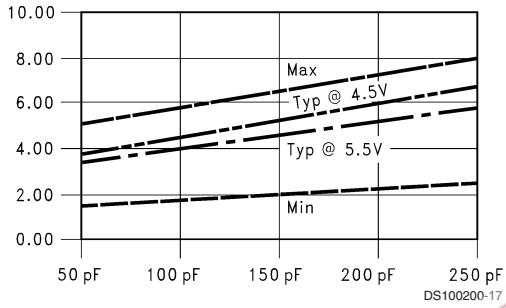
t_{PLH} vs Load Capacitance
1 Output Switching, $T_A = 25^\circ\text{C}$



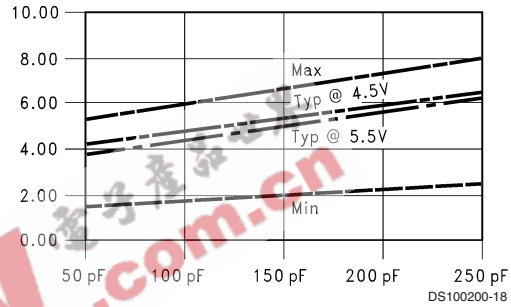
t_{PHL} vs Load Capacitance
1 Output Switching, $T_A = 25^\circ\text{C}$



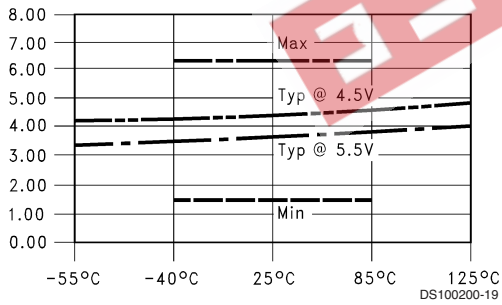
t_{PLH} vs Load Capacitance
16 Outputs Switching, $T_A = 25^\circ\text{C}$



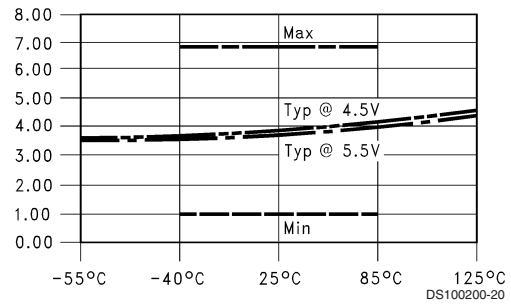
t_{PHL} vs Load Capacitance
16 Outputs Switching, $T_A = 25^\circ\text{C}$



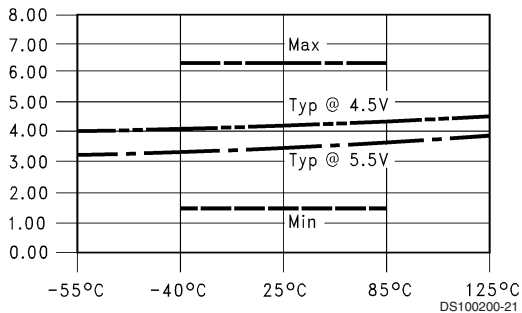
t_{PZL} vs Temperature (T_A)
 $C_L = 50\text{ pF}$, 1 Output Switching



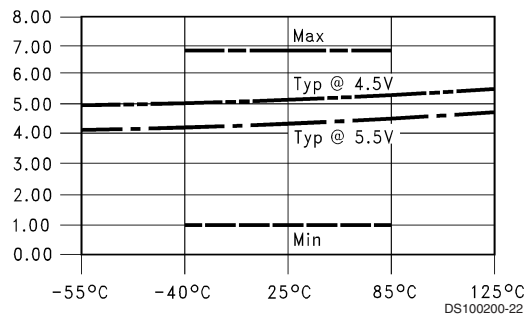
t_{PLZ} vs Temperature (T_A)
 $C_L = 50\text{ pF}$, 1 Output Switching



t_{PZH} vs Temperature (T_A)
 $C_L = 50\text{ pF}$, 1 Output Switching



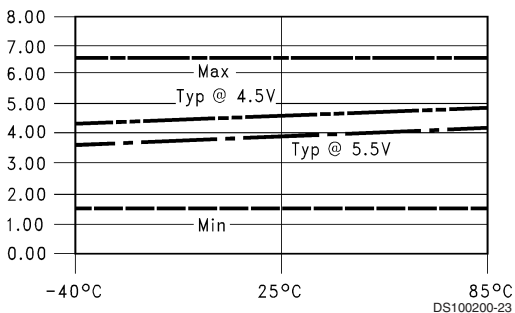
t_{PHZ} vs Temperature (T_A)
 $C_L = 50\text{ pF}$, 1 Output Switching



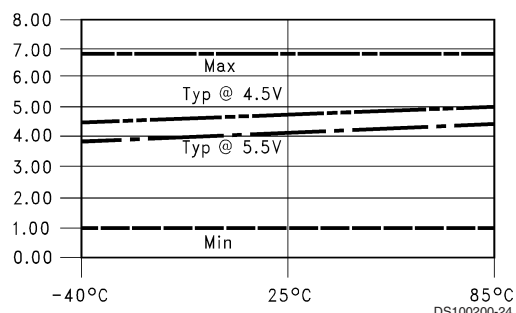
Dashed lines represent design characteristics; for specified guarantees, refer to AC Characteristics Table.

Capacitance (Continued)

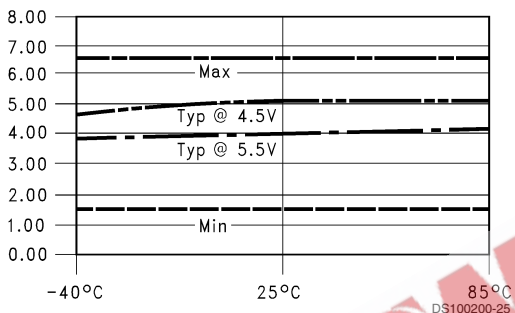
t_{PZH} vs Temperature (T_A)
 $C_L = 50$ pF, 16 Outputs Switching



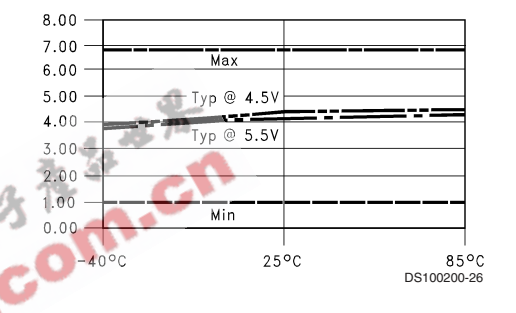
t_{PHZ} vs Temperature (T_A)
 $C_L = 50$ pF, 16 Outputs Switching



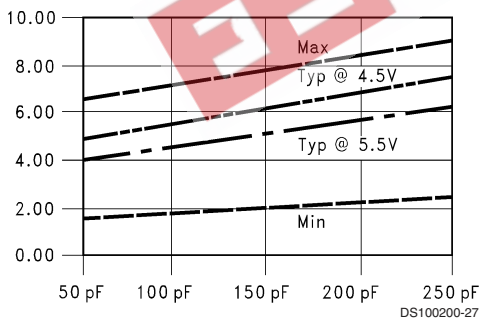
t_{PZL} vs Temperature (T_A)
 $C_L = 50$ pF, 16 Outputs Switching



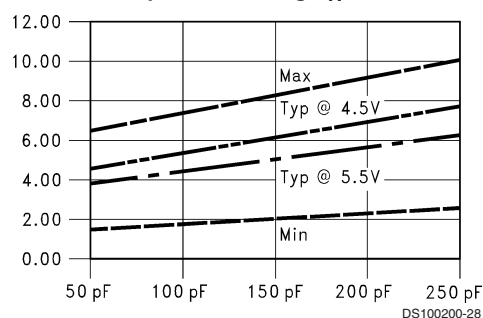
t_{PLZ} vs Temperature (T_A)
 $C_L = 50$ pF, 16 Outputs Switching



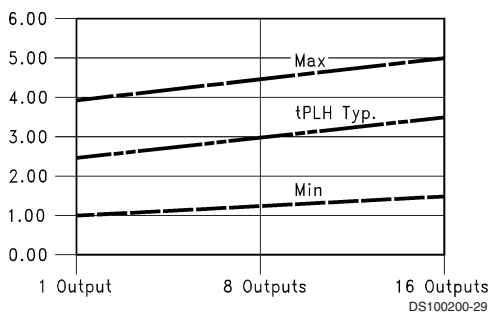
t_{PZL} vs Load Capacitance
 16 Outputs Switching $T_A = 25^\circ\text{C}$



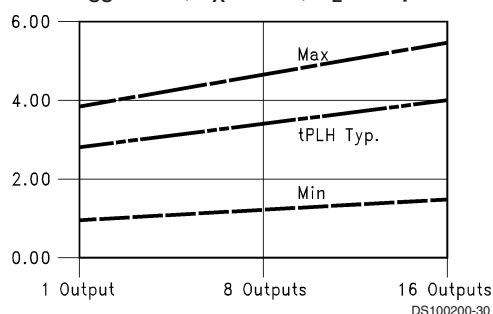
t_{PZH} vs Load Capacitance
 16 Outputs Switching $T_A = 25^\circ\text{C}$



t_{PLH} vs Number Output Switching
 $V_{CC} = 5.0\text{V}$, $T_A = 25^\circ\text{C}$, $C_L = 50$ pF



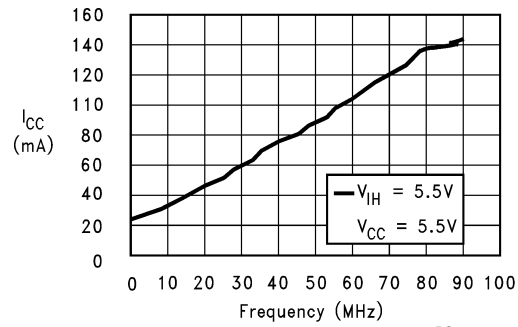
t_{PHL} vs Number Output Switching
 $V_{CC} = 5.0\text{V}$, $T_A = 25^\circ\text{C}$, $C_L = 50$ pF



Dashed lines represent design characteristics; for specified guarantees, refer to AC Characteristics Table.

Capacitance (Continued)

I_{CC} vs Frequency
 Average, $T_A = 25^\circ\text{C}$, $V_{CC} = 5.5\text{V}$
 All Outputs Unloaded/Unterminated;
 16 Outputs Switching In-Phase at 50% Duty Cycle

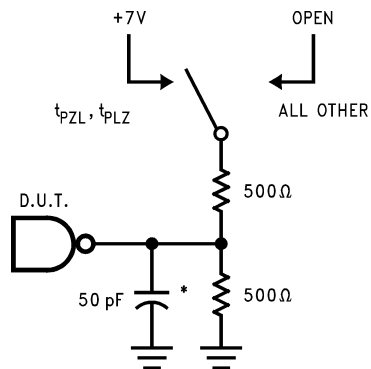


DS100200-31

Dashed lines represent design characteristics; for specified guarantees, refer to AC Characteristics Table.

EEPW 电子产品世界
 .com.cn

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

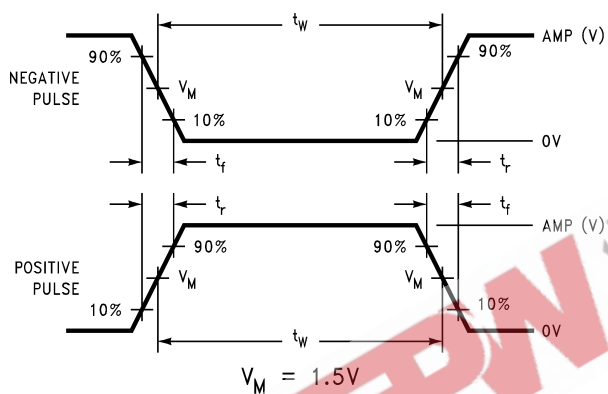


FIGURE 2. Input Pulse Requirements

Amplitude	Rep. Rate	t_w	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

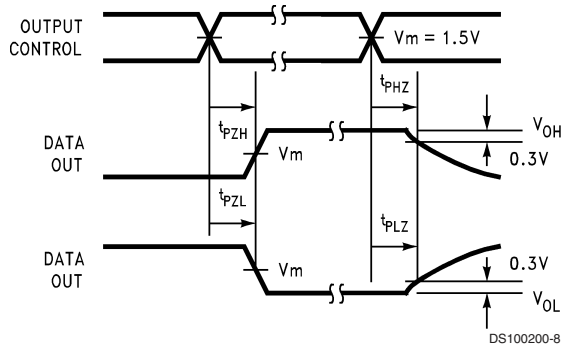


FIGURE 4. TRI-STATE Output HIGH and LOW Enable and Disable Times

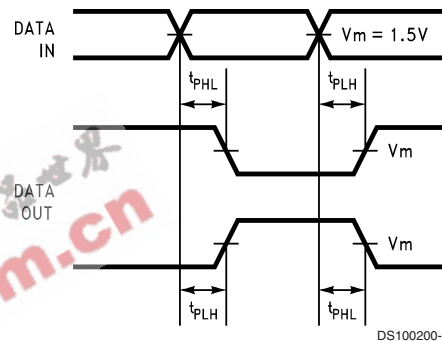
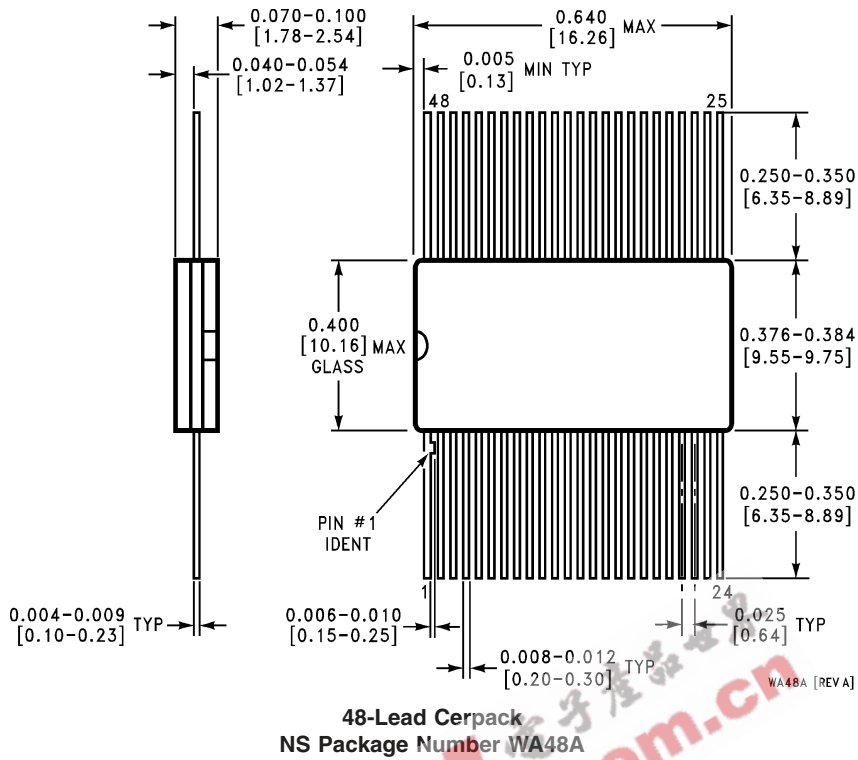


FIGURE 5. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

Physical Dimensions inches (millimeters) unless otherwise noted



LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

BANNED SUBSTANCE COMPLIANCE

National Semiconductor certifies that the products and packing materials meet the provisions of the Customer Products Stewardship Specification (CSP-9-111C2) and the Banned Substances and Materials of Interest Specification (CSP-9-111S2) and contain no "Banned Substances" as defined in CSP-9-111S2.



National Semiconductor
Americas Customer
Support Center
Email: new.feedback@nsc.com
Tel: 1-800-272-9959

National Semiconductor
Europe Customer Support Center
Fax: +49 (0) 180-530 85 86
Email: europe.support@nsc.com
Deutsch Tel: +49 (0) 69 9508 6208
English Tel: +44 (0) 870 24 0 2171
Français Tel: +33 (0) 1 41 91 8790

National Semiconductor
Asia Pacific Customer
Support Center
Email: ap.support@nsc.com

National Semiconductor
Japan Customer Support Center
Fax: 81-3-5639-7507
Email: jpn.feedback@nsc.com
Tel: 81-3-5639-7560

www.national.com